

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>VB20100C-M3/8W</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VB20100C-M3/8W - DIODE SCHOTTKY 20A 100V TO-263AB Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



COMPLIANT

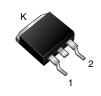


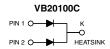
Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.50 \text{ V}$ at $I_F = 5 \text{ A}$

TMBS®





PRIMARY CHARACTERISTICS				
Package TO-263AB				
I _{F(AV)}	2 x 10 A			
V_{RRM}	100 V			
I _{FSM}	150 A			
V _F at I _F = 10 A	0.58 V			
T _J max.	150 °C			
Diode variation	Common cathode			

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses

High efficiency operation

Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C

HALOGEN

FREE

 Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VB20100C	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	100	V
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	20	^
	per diode		10	A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150	А
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 150	°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode (1)	I _F = 5 A	T _A = 25 °C	V _F	0.55	-	V	
	I _F = 10 A			0.65	0.79		
	I _F = 5 A	T _A = 125 °C		0.50	-		
	I _F = 10 A			0.58	0.68		
Reverse current per diode (2)	V _R = 70 V	T _A = 25 °C	· I _R	17	-	μA	
	v _R = 70 v	T _A = 125 °C		5.3	-	mA	
	V _R = 100 V	T _A = 25 °C		-	800	μA	
	v _R = 100 v	T _A = 125 °C		12	25	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width $\leq 40 \text{ ms}$

Revision: 15-May-13 Document Number: 87982





TO-263AB

VB20100C-M3

°C/W

Tape and reel

Vishay General Semiconductor

2.8

800/reel

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VB20100C	UNIT			

Raic

8W

7			000				
ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-263AB	VB20100C-M3/4W	1.39	4W	50/tube	Tube		

1.39

RATINGS AND CHARACTERISTICS CURVES

VB20100C-M3/8W

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(T_A = 25 °C unless otherwise noted)

Typical thermal resistance per diode

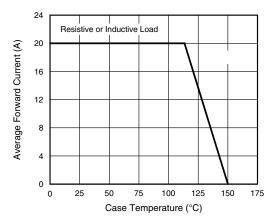


Fig. 1 - Maximum Forward Current Derating Curve

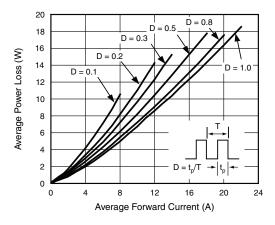


Fig. 2 - Forward Power Loss Characteristics Per Diode

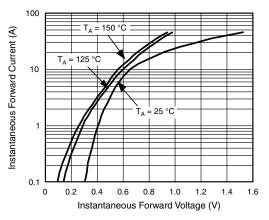


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

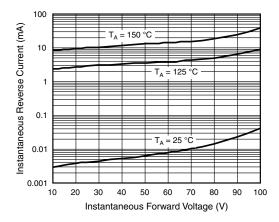


Fig. 4 - Typical Reverse Characteristics Per Diode

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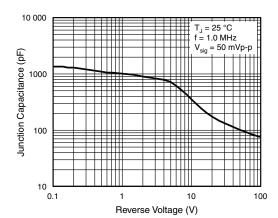


Fig. 5 - Typical Junction Capacitance Per Diode

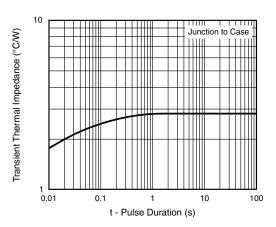
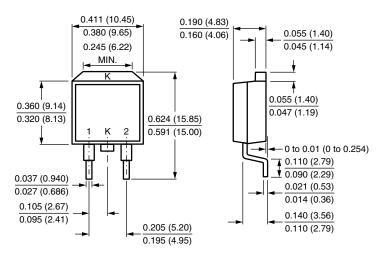


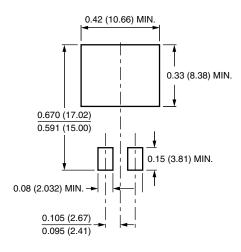
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB



Mounting Pad Layout





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